



CPH6538 — NPN Epitaxial Planar Silicon Transistor

DC / DC Converter Applications

Features

- Small-sized package with two NPN transistors (30C02CH equivalency) contained in one package
- $V_{CEO}=30V, I_C=0.7A$
- Low Collector-to-Emitter Saturation Voltage $V_{CE(sat)}=85mV(\text{typ.})@I_C=0.2A$
- High-speed switching $t_f=40ns(\text{typ.})@I_C=0.3A$
- Halogen free Compliance

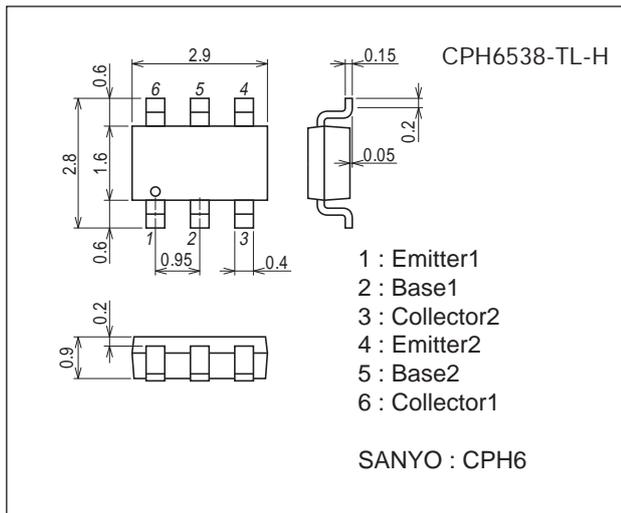
Specifications

Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		40	V
Collector-to-Emitter Voltage	V_{CEO}		30	V
Emitter-to-Base Voltage	V_{EBO}		5	V
Collector Current	I_C		700	mA
Collector Current (Pulse)	I_{CP}		1.4	A
Collector Dissipation	PC	When mounted on ceramic substrate (600mm ² ×0.8mm) 1unit	0.6	W
Junction Temperature	T_j		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Package Dimensions

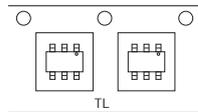
unit : mm (typ)
7018A-006



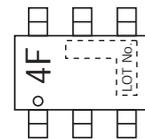
Product & Package Information

- Package : CPH6
- JEITA, JEDEC : SC-74, SOT-26, SOT-457
- Minimum Packing Quantity : 3,000 pcs./reel

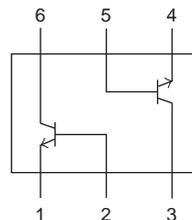
Packing Type: TL



Marking



Electrical Connection

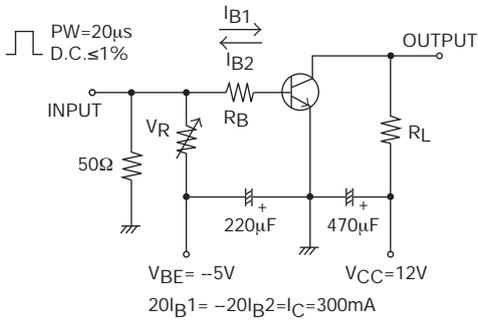


CPH6538

Electrical Characteristics at $T_a=25^\circ\text{C}$

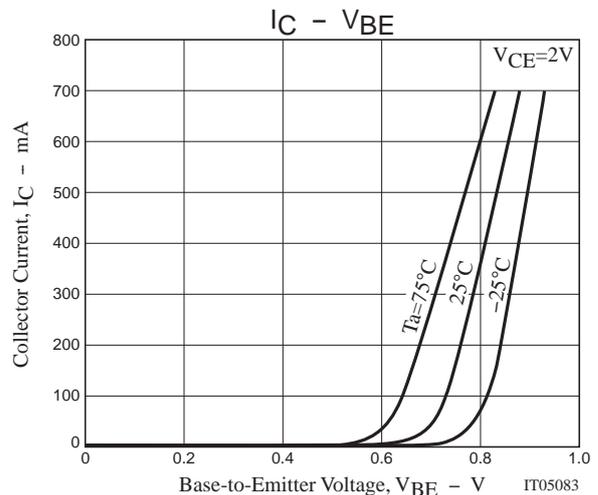
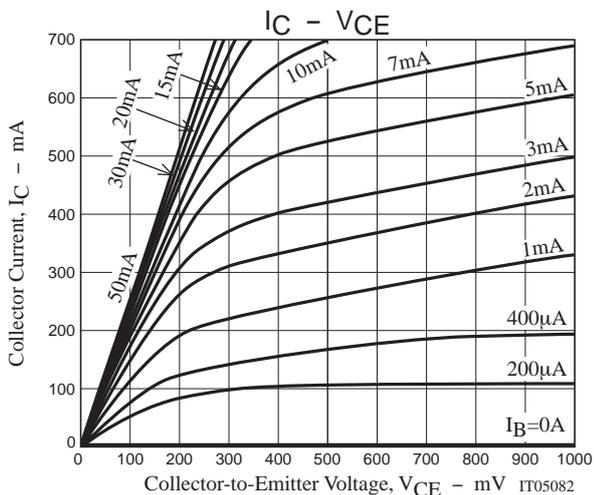
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=30\text{V}, I_E=0\text{A}$			100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0\text{A}$			100	nA
DC Current Gain	h_{FE}	$V_{CE}=2\text{V}, I_C=50\text{mA}$	300		800	
Gain-Bandwidth Product	f_T	$V_{CE}=2\text{V}, I_C=50\text{mA}$		540		MHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, f=1\text{MHz}$		3.3		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=200\text{mA}, I_B=10\text{mA}$		85	190	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=200\text{mA}, I_B=10\text{mA}$		0.9	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0\text{A}$	40			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, R_{BE}=\infty$	30			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0\text{A}$	5			V
Turn-On Time	t_{on}	See specified Test Circuit.		35		ns
Storage Time	t_{stg}			255		ns
Fall Time	t_f			40		ns

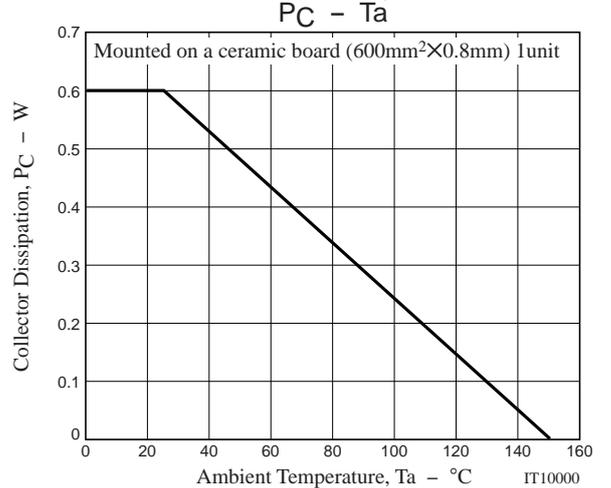
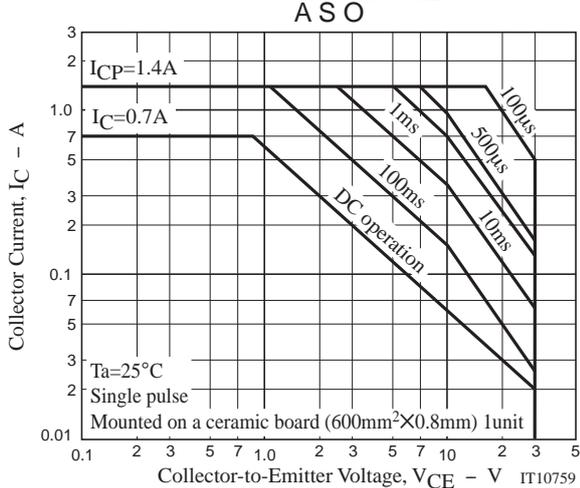
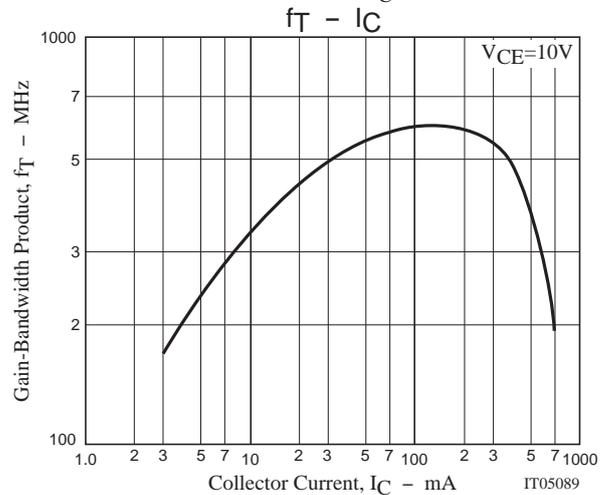
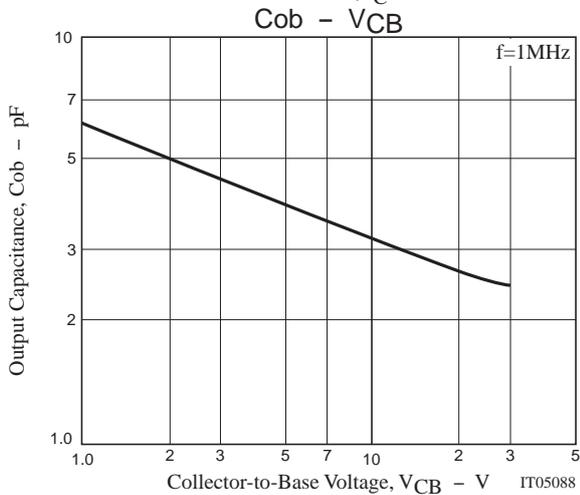
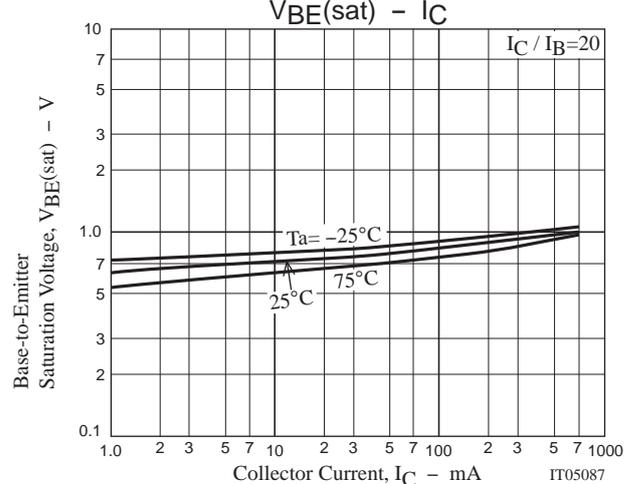
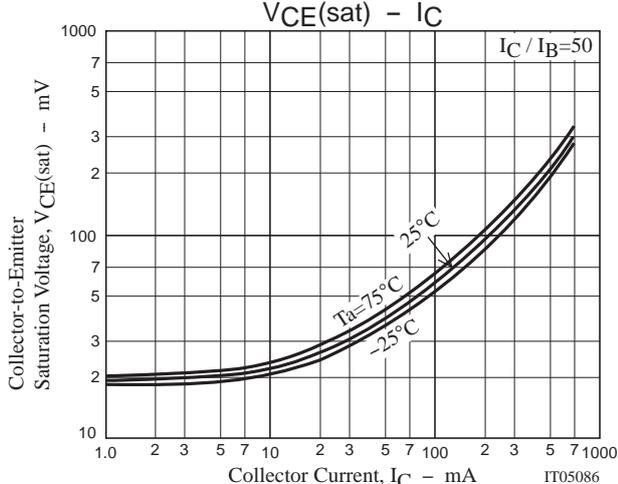
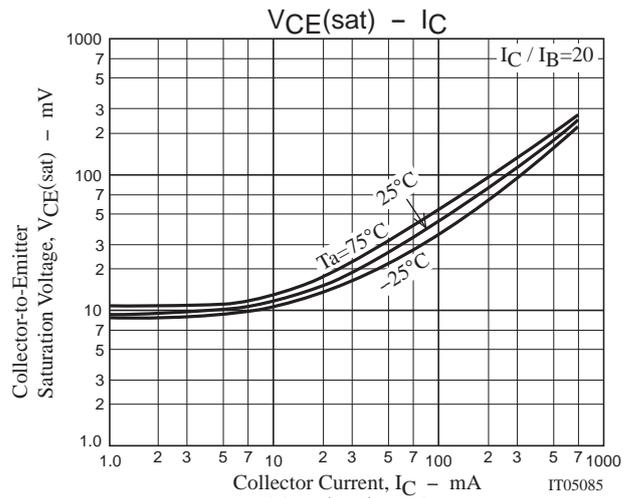
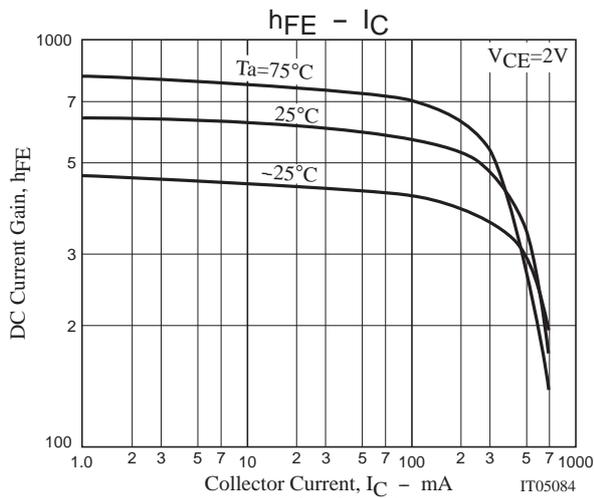
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
CPH6538-TL-H	CPH6	3,000pcs./reel	Pb Free and Halogen Free



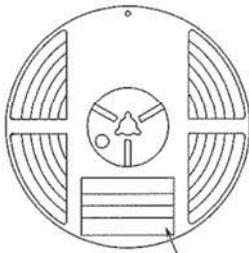


Embossed Taping Specification
CPH6538-TL-H

1. Packing Format

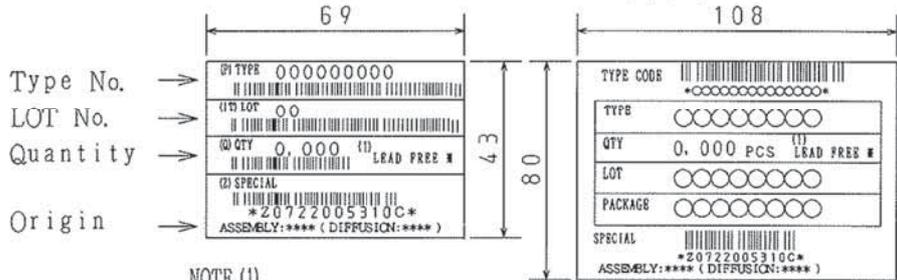
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH6	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



Reel label

Reel label, Inner box label (unit:mm) Outer box label
It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



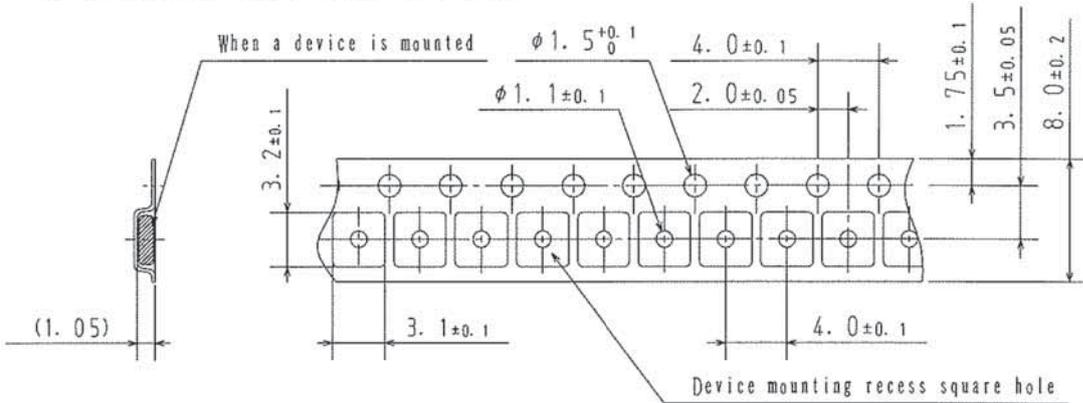
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

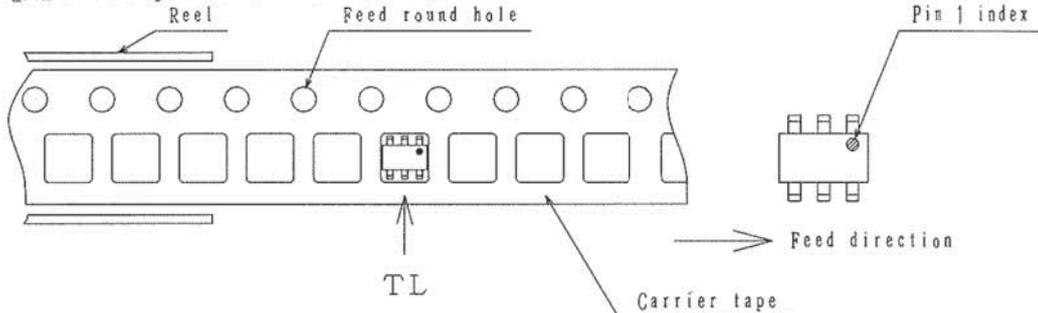
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



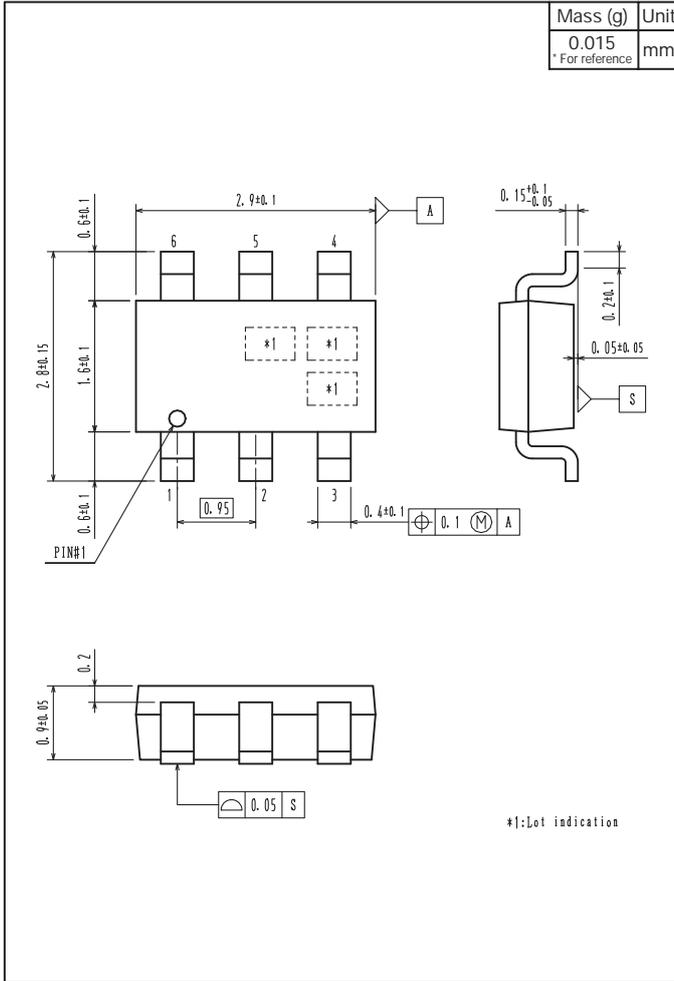
2-2. Device placement direction



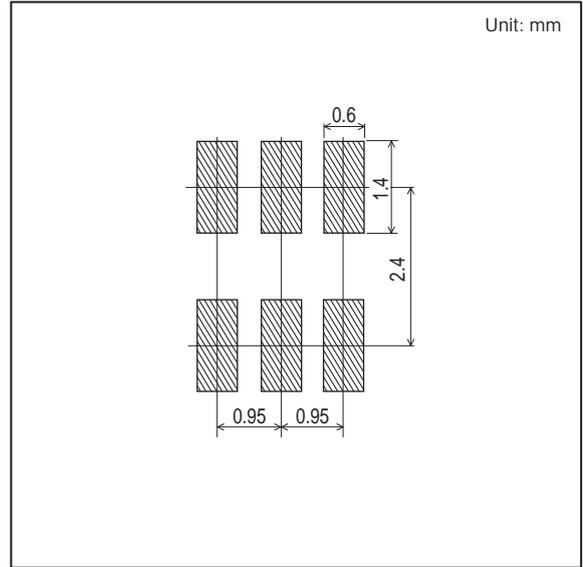
Those with pin 1 index on the feed hole side.....TL

CPH6538

Outline Drawing CPH6538-TL-H



Land Pattern Example



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